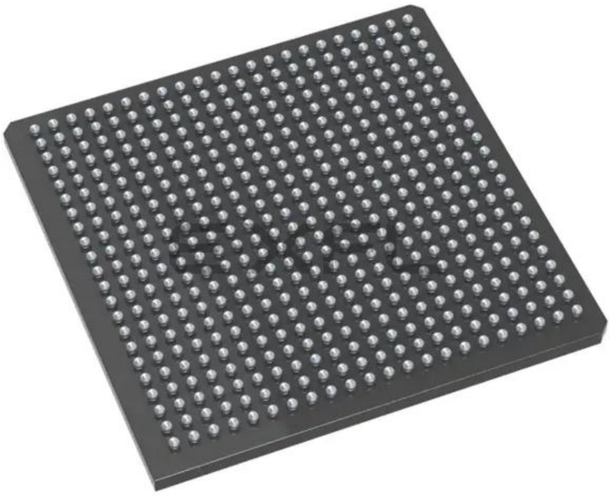
Microchip Technology - A3PE3000-1FG484 Datasheet



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The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	516096
Number of I/O	341
Number of Gates	3000000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	484-BGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a3pe3000-1fg484

Table 2-8 • **Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings (continued)**

	VMV (V)	Static Power PDC2 (mW)[1]	Dynamic Power PAC9 (µW/MHz)[2]
HSTL (I)	1.5	0.17	2.03
HSTL (II)	1.5	0.17	2.03
SSTL2 (I)	2.5	1.38	4.48
SSTL2 (II)	2.5	1.38	4.48
SSTL3 (I)	3.3	3.21	9.26
SSTL3 (II)	3.3	3.21	9.26
Differential			
LVDS/B-LVDS/M-LVDS	2.5	2.26	1.50
LVPECL	3.3	5.71	2.17

Notes:

1. *PDC2 is the static power (where applicable) measured on VMV.*
2. *PAC9 is the total dynamic power measured on VCC and VMV.*
3. *All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8b specification.*

Table 2-9 • **Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings** [1]

	C_{LOAD} (pF)	VCCI (V)	Static Power PDC3 (mW)[2]	Dynamic Power PAC10 (µW/MHz)[3]
Single-Ended				
3.3 V LVTTL/LVCMOS	35	3.3	–	474.70
3.3 V LVTTL/LVCMOS Wide Range[4]	35	3.3	–	474.70
2.5 V LVCMOS	35	2.5	–	270.73
1.8 V LVCMOS	35	1.8	–	151.78
1.5 V LVCMOS (JESD8-11)	35	1.5	–	104.55
3.3 V PCI	10	3.3	–	204.61
3.3 V PCI-X	10	3.3	–	204.61
Voltage-Referenced				
3.3 V GTL	10	3.3	–	24.08
2.5 V GTL	10	2.5	–	13.52
3.3 V GTL+	10	3.3	–	24.10
2.5 V GTL+	10	2.5	–	13.54
HSTL (I)	20	1.5	7.08	26.22
HSTL (II)	20	1.5	13.88	27.22
SSTL2 (I)	30	2.5	16.69	105.56
SSTL2 (II)	30	2.5	25.91	116.60

Notes:

1. *Dynamic power consumption is given for standard load and software default drive strength and output slew.*
2. *PDC3 is the static power (where applicable) measured on VCCI.*
3. *PAC10 is the total dynamic power measured on VCC and VCCI.*
4. *All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.*

Table 2-9 **• Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings (continued) (continued)[1]**

	C_{LOAD} (pF)	VCCI (V)	Static Power PDC3 (mW)[2]	Dynamic Power PAC10 (µW/MHz)[3]
SSTL3 (I)	30	3.3	26.02	114.87
SSTL3 (II)	30	3.3	42.21	131.76
Differential				
LVDS/B-LVDS/M-LVDS	–	2.5	7.70	89.62
LVPECL	–	3.3	19.42	168.02

Notes:

1. *Dynamic power consumption is given for standard load and software default drive strength and output slew.*
2. *PDC3 is the static power (where applicable) measured on VCCI.*
3. *PAC10 is the total dynamic power measured on VCC and VCCI.*
4. *All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.*

Power Consumption of Various Internal Resources

Table 2-10 **• Different Components Contributing to the Dynamic Power Consumption in ProASIC3E Devices**

Parameter	Definition	Device-Specific Dynamic Contributions (µW/MHz) A3PE600	A3PE1500	A3PE3000
PAC1	Clock contribution of a Global Rib	12.77	16.21	19.7
PAC2	Clock contribution of a Global Spine	1.85	3.06	4.16
PAC3	Clock contribution of a VersaTile row	0.88		
PAC4	Clock contribution of a VersaTile used as a sequential module	0.12		
PAC5	First contribution of a VersaTile used as a sequential module	0.07		
PAC6	Second contribution of a VersaTile used as a sequential module	0.29		
PAC7	Contribution of a VersaTile used as a combinatorial module	0.29		
PAC8	Average contribution of a routing net	0.70		
PAC9	Contribution of an I/O input pin (standard-dependent)	See Table 2-8 on page 2-6.		
PAC10	Contribution of an I/O output pin (standard-dependent)	See Table 2-9 on page 2-7		
PAC11	Average contribution of a RAM block during a read operation	25.00		
PAC12	Average contribution of a RAM block during a write operation	30.00		
PAC13	Static PLL contribution	2.55 mW		
PAC14	Dynamic contribution for PLL	2.60		

Note: For a different output load, drive strength, or slew rate, Microsemi recommends using the Microsemi power calculator or SmartPower in Libero SoC.

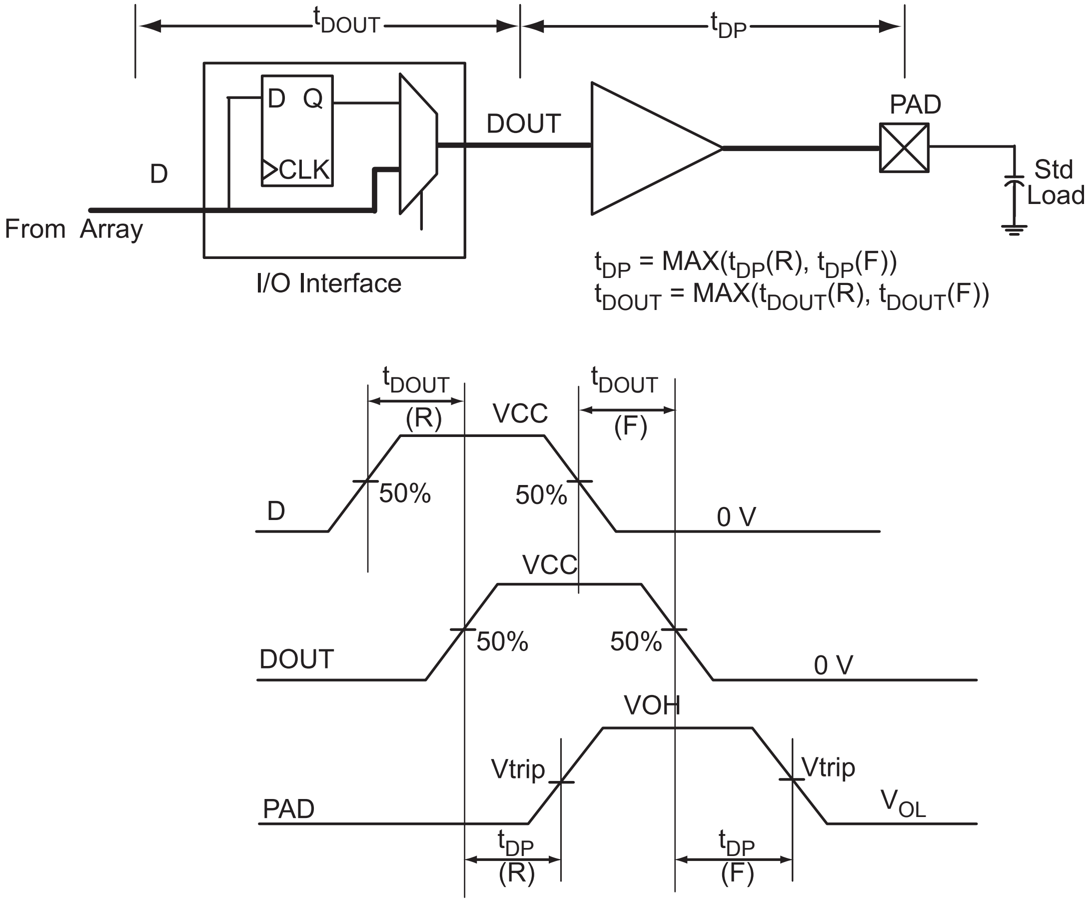

Figure 2-4 • **Output Buffer Model and Delays (example)**

Table 2-17 • **Summary of I/O Timing Characteristics—Software Default Settings**
–2 Speed Grade, Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V

I/O Standard	Drive Strength (mA)	Equivalent Software Default Drive Strength Option)[1]	Slew Rate	Capacitive Load (pF)	External Resistor (Ω)	t_{DOUT} (ns)	t_{DP} (ns)	t_{DIN} (ns)	t_{PY} (ns)	t_{PYS} (ns)	t_{EOUT} (ns)	t_{ZL} (ns)	t_{ZH} (ns)	t_{LZ} (ns)	t_{HZ} (ns)	t_{ZLS} (ns)	t_{ZHS} (ns)
3.3 V LVTTL / 3.3 V LVCMOS	12	12	High	35	–	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81
3.3 V LVCMOS Wide Range[2]	100 µA	12	High	35	–	0.49	4.24	0.03	1.36	1.78	0.32	4.24	3.25	3.78	4.17	6.77	5.79
2.5 V LVCMOS	12	12	High	35	–	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28
1.8 V LVCMOS	12	12	High	35	–	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98
1.5 V LVCMOS	12	12	High	35	–	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37
3.3 V PCI	Per PCI spec	–	High	10	25 [3]	0.49	2.09	0.03	0.78	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16
3.3 V PCI-X	Per PCI-X spec	–	High	10	25[3]	0.49	2.09	0.03	0.78	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16
3.3 V GTL	20 [4]	–	High	10	25	0.45	1.55	0.03	2.19	–	0.32	1.52	1.55	–	–	3.19	3.22
2.5 V GTL	20 [4]	–	High	10	25	0.45	1.59	0.03	1.83	–	0.32	1.61	1.59	–	–	3.28	3.26
3.3 V GTL+	35	–	High	10	25	0.45	1.53	0.03	1.19	–	0.32	1.56	1.53	–	–	3.23	3.20
2.5 V GTL+	33	–	High	10	25	0.45	1.65	0.03	1.13	–	0.32	1.68	1.57	–	–	3.35	3.24
HSTL (I)	8	–	High	20	50	0.49	2.37	0.03	1.59	–	0.32	2.42	2.35	–	–	4.09	4.02
HSTL (II)	15 [4]	–	High	20	25	0.49	2.26	0.03	1.59	–	0.32	2.30	2.03	–	–	3.97	3.70
SSTL2 (I)	15	–	High	30	50	0.49	1.59	0.03	1.00	–	0.32	1.62	1.38	–	–	3.29	3.05
SSTL2 (II)	18	–	High	30	25	0.49	1.62	0.03	1.00	–	0.32	1.65	1.32	–	–	3.32	2.99
SSTL3 (I)	14	–	High	30	50	0.49	1.72	0.03	0.93	–	0.32	1.75	1.37	–	–	3.42	3.04
SSTL3 (II)	21	–	High	30	25	0.49	1.54	0.03	0.93	–	0.32	1.57	1.25	–	–	3.24	2.92
LVDS/B-LVDS/ M-LVDS	24	–	High	–	–	0.49	1.40	0.03	1.36	–	–	–	–	–	–	–	–
LVPECL	24	–	High	–	–	0.49	1.36	0.03	1.22	–	–	–	–	–	–	–	–

Notes:

1. *The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 µA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.*
2. *All LVCMOS 3.3 V software macros support LVCMOS 3.3V wide range as specified in the JESD8b specification.*
3. *Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-11 on page 2-38 for connectivity. This resistor is not required during normal operation.*
4. *Output drive strength is below JEDEC specification.*
5. *For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5.*

***Table 2-21* • I/O Short Currents IOSH/IOSL**

	Drive Strength	IOSH (mA)*	IOSL (mA)*
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	25	27
	4 mA	25	27
	6 mA	51	54
	8 mA	51	54
	12 mA	103	109
	16 mA	132	127
	24 mA	268	181
3.3 V LVCMOS Wide Range	100 µA	Same as regular 3.3 V LVCMOS	Same as regular 3.3 V LVCMOS
2.5 V LVCMOS	4 mA	16	18
	8 mA	32	37
	12 mA	65	74
	16 mA	83	87
	24 mA	169	124
1.8 V LVCMOS	2 mA	9	11
	4 mA	17	22
	6 mA	35	44
	8 mA	45	51
	12 mA	91	74
	16 mA	91	74
1.5 V LVCMOS	2 mA	13	16
	4 mA	25	33
	6 mA	32	39
	8 mA	66	55
	12 mA	66	55

Notes:

1. *T_J = 100°C*
2. *Applicable to 3.3 V LVCMOS Wide Range. IOSL/IOSH dependent on the I/O buffer drive strength selected for wide range applications. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8b specification.*

The length of time an I/O can withstand IOSH/IOSL events depends on the junction temperature. The reliability data below is based on a 3.3 V, 36 mA I/O setting, which is the worst case for this type of analysis.

For example, at 100°C, the short current condition would have to be sustained for more than six months to cause a reliability concern. The I/O design does not contain any short circuit protection, but such protection would only be needed in extremely prolonged stress conditions.

***Table 2-22* • Duration of Short Circuit Event Before Failure**

Temperature	Time before Failure
–40°C	> 20 years
0°C	> 20 years
25°C	> 20 years
70°C	5 years

***Table 2-36* • 2.5 V LVCMOS Low Slew**
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.3 V

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
4 mA	Std.	0.66	12.00	0.04	1.51	1.66	0.43	12.23	11.61	2.72	2.20	14.46	13.85	ns
	–1	0.56	10.21	0.04	1.29	1.41	0.36	10.40	9.88	2.31	1.87	12.30	11.78	ns
	–2	0.49	8.96	0.03	1.13	1.24	0.32	9.13	8.67	2.03	1.64	10.80	10.34	ns
8 mA	Std.	0.66	8.73	0.04	1.51	1.66	0.43	8.89	8.01	3.10	2.93	11.13	10.25	ns
	–1	0.56	7.43	0.04	1.29	1.41	0.36	7.57	6.82	2.64	2.49	9.47	8.72	ns
	–2	0.49	6.52	0.03	1.13	1.24	0.32	6.64	5.98	2.32	2.19	8.31	7.65	ns
12 mA	Std.	0.66	6.77	0.04	1.51	1.66	0.43	6.90	6.11	3.37	3.39	9.14	8.34	ns
	–1	0.56	5.76	0.04	1.29	1.41	0.36	5.87	5.20	2.86	2.89	7.77	7.10	ns
	–2	0.49	5.06	0.03	1.13	1.24	0.32	5.15	4.56	2.51	2.53	6.82	6.23	ns
16 mA	Std.	0.66	6.31	0.04	1.51	1.66	0.43	6.42	5.73	3.42	3.52	8.66	7.96	ns
	–1	0.56	5.37	0.04	1.29	1.41	0.36	5.46	4.87	2.91	3.00	7.37	6.77	ns
	–2	0.49	4.71	0.03	1.13	1.24	0.32	4.80	4.28	2.56	2.63	6.47	5.95	ns
24 mA	Std.	0.66	5.93	0.04	1.51	1.66	0.43	6.04	5.70	3.49	4.00	8.28	7.94	ns
	–1	0.56	5.05	0.04	1.29	1.41	0.36	5.14	4.85	2.97	3.40	7.04	6.75	ns
	–2	0.49	4.43	0.03	1.13	1.24	0.32	4.51	4.26	2.61	2.99	6.18	5.93	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

Table 2-84 • **Parameter Definition and Measuring Nodes**

Parameter Name	Parameter Definition	Measuring Nodes (from, to)*
t_{OCLKQ}	Clock-to-Q of the Output Data Register	H, DOUT
t_{OSUD}	Data Setup Time for the Output Data Register	F, H
t_{OHD}	Data Hold Time for the Output Data Register	F, H
t_{OSUE}	Enable Setup Time for the Output Data Register	G, H
t_{OHE}	Enable Hold Time for the Output Data Register	G, H
t_{OPRE2Q}	Asynchronous Preset-to-Q of the Output Data Register	L, DOUT
$t_{OREMPRE}$	Asynchronous Preset Removal Time for the Output Data Register	L, H
$t_{ORECPRE}$	Asynchronous Preset Recovery Time for the Output Data Register	L, H
t_{OECLKQ}	Clock-to-Q of the Output Enable Register	H, EOUT
t_{OESUD}	Data Setup Time for the Output Enable Register	J, H
t_{OEHD}	Data Hold Time for the Output Enable Register	J, H
t_{OESUE}	Enable Setup Time for the Output Enable Register	K, H
t_{OEHE}	Enable Hold Time for the Output Enable Register	K, H
$t_{OEPRE2Q}$	Asynchronous Preset-to-Q of the Output Enable Register	I, EOUT
$t_{OEREMPRE}$	Asynchronous Preset Removal Time for the Output Enable Register	I, H
$t_{OERECPRE}$	Asynchronous Preset Recovery Time for the Output Enable Register	I, H
t_{ICLKQ}	Clock-to-Q of the Input Data Register	A, E
t_{ISUD}	Data Setup Time for the Input Data Register	C, A
t_{IHD}	Data Hold Time for the Input Data Register	C, A
t_{ISUE}	Enable Setup Time for the Input Data Register	B, A
t_{IHE}	Enable Hold Time for the Input Data Register	B, A
t_{IPRE2Q}	Asynchronous Preset-to-Q of the Input Data Register	D, E
$t_{IREMPRE}$	Asynchronous Preset Removal Time for the Input Data Register	D, A
$t_{IRECPRE}$	Asynchronous Preset Recovery Time for the Input Data Register	D, A

Note: *See Figure 2-25 on page 2-53 for more information.

Output DDR Module

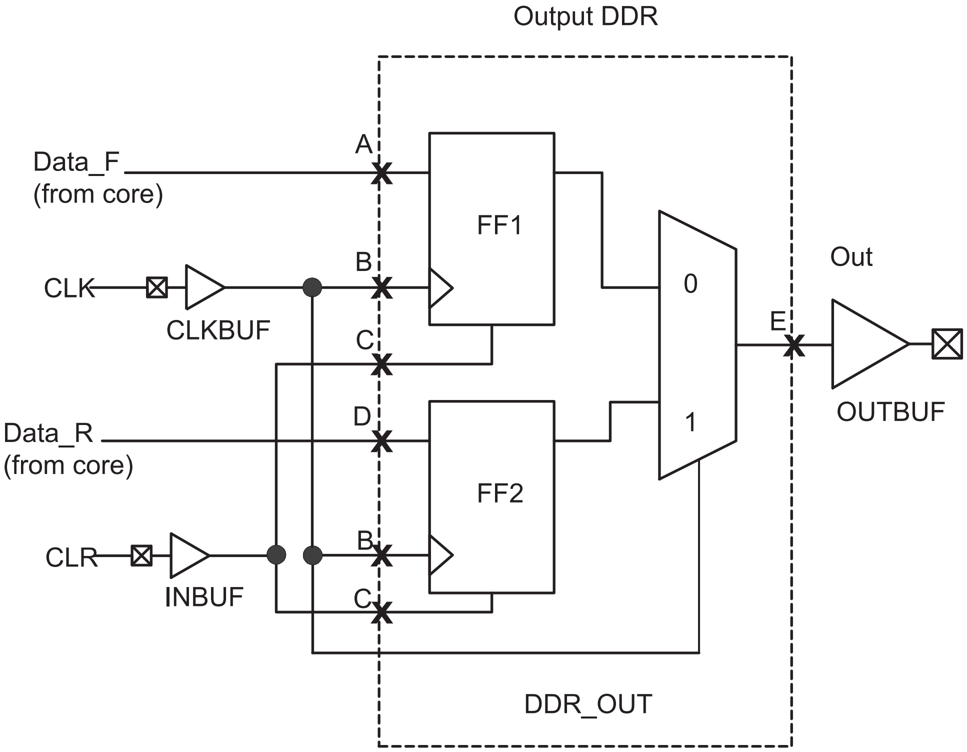

Figure 2-32 • **Output DDR Timing Model**

Table 2-91 • **Parameter Definitions**

Parameter Name	Parameter Definition	Measuring Nodes (from, to)
$t_{DDROCLKQ}$	Clock-to-Out	B, E
$t_{DDROCLR2Q}$	Asynchronous Clear-to-Out	C, E
$t_{DDROREMCLR}$	Clear Removal	C, B
$t_{DDRORECCLR}$	Clear Recovery	C, B
$t_{DDROSUD1}$	Data Setup Data_F	A, B
$t_{DDROSUD2}$	Data Setup Data_R	D, B
$t_{DDROHD1}$	Data Hold Data_F	A, B
$t_{DDROHD2}$	Data Hold Data_R	D, B

Global Resource Characteristics

A3PE600 Clock Tree Topology

Clock delays are device-specific. Figure 2-38 is an example of a global tree used for clock routing. The global tree presented in Figure 2-38 is driven by a CCC located on the west side of the A3PE600 device. It is used to drive all D-flip-flops in the device.

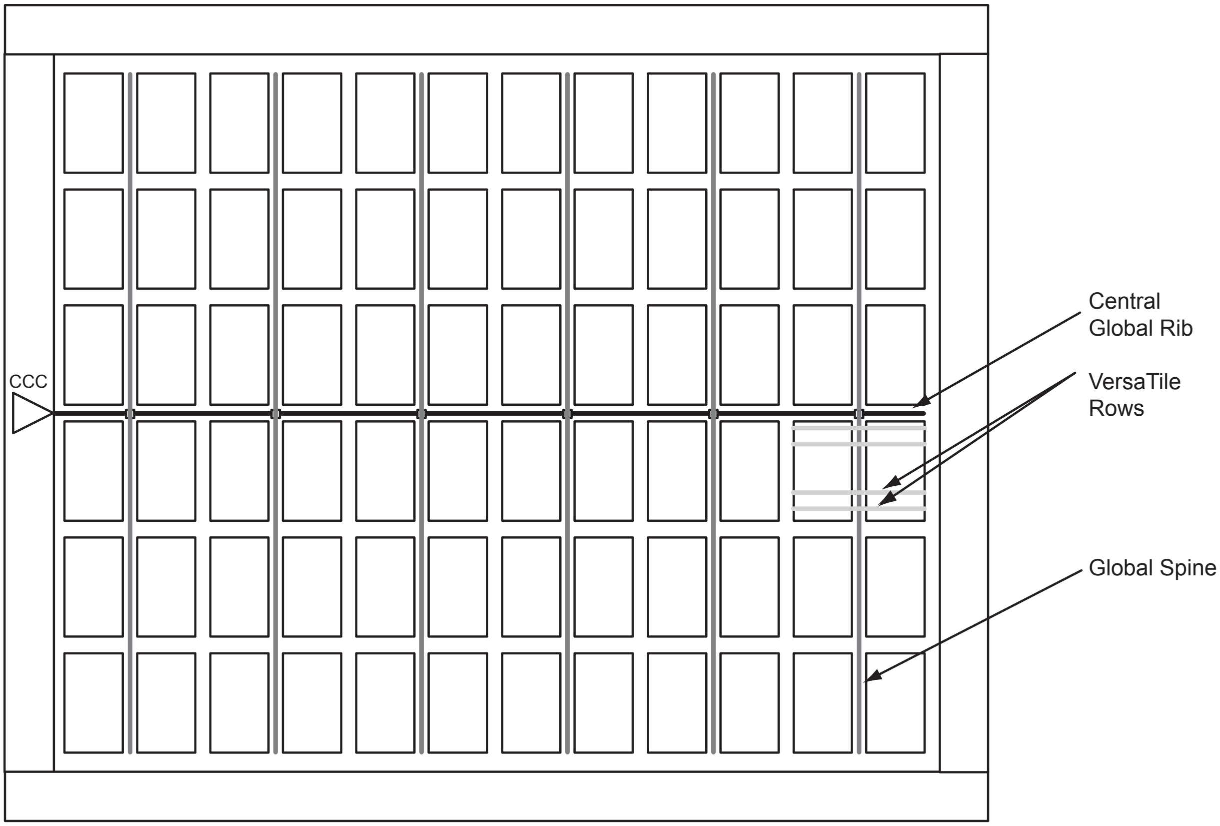

Figure 2-38 • **Example of Global Tree Use in an A3PE600 Device for Clock Routing**

Global Tree Timing Characteristics

Global clock delays include the central rib delay, the spine delay, and the row delay. Delays do not include I/O input buffer clock delays, as these are I/O standard–dependent, and the clock may be driven and conditioned internally by the CCC module. For more details on clock conditioning capabilities, refer to the "Clock Conditioning Circuits" section on page 2-70. Table 2-95 on page 2-69, Table 2-96 on page 2-69, and Table 2-97 on page 2-69 present minimum and maximum global clock delays within the device. Minimum and maximum delays are measured with minimum and maximum loading.

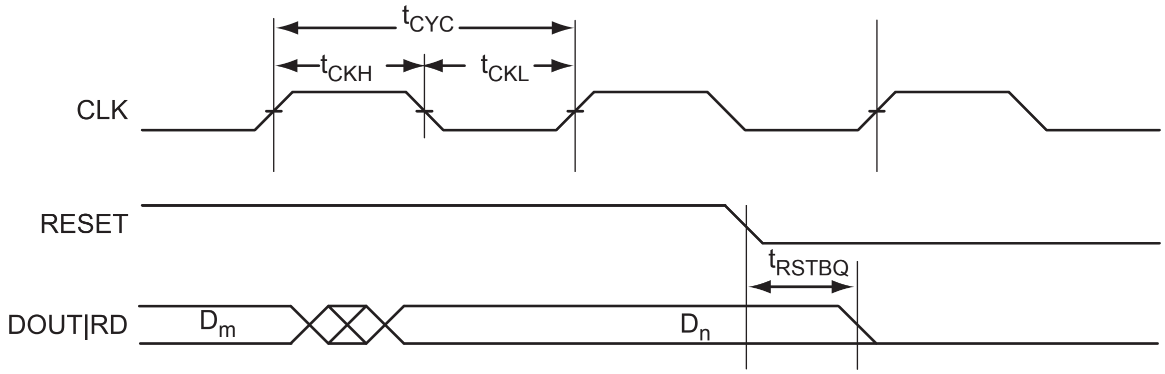

***Figure 2-45* • RAM Reset. Applicable to Both RAM4K9 and RAM512x18.**

FIFO

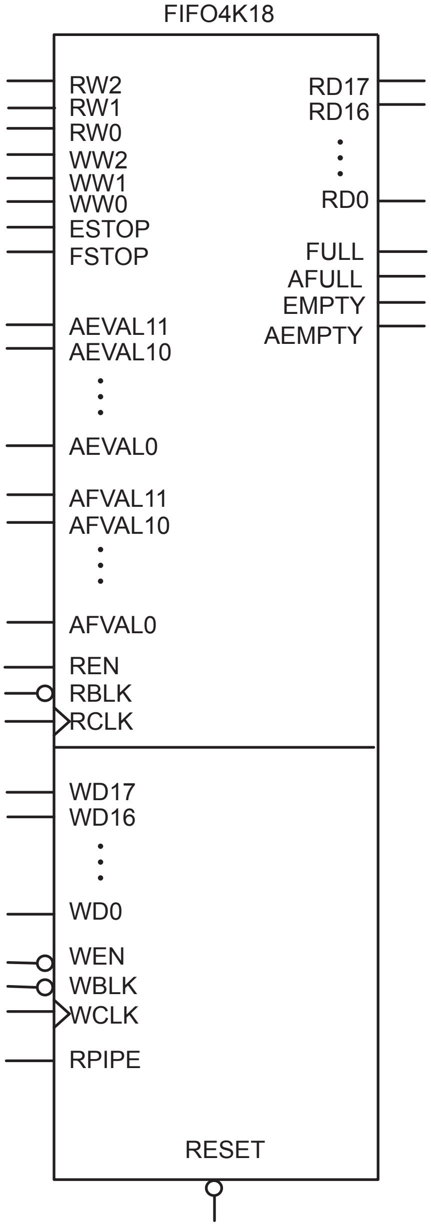

Figure 2-46 **• FIFO Model**

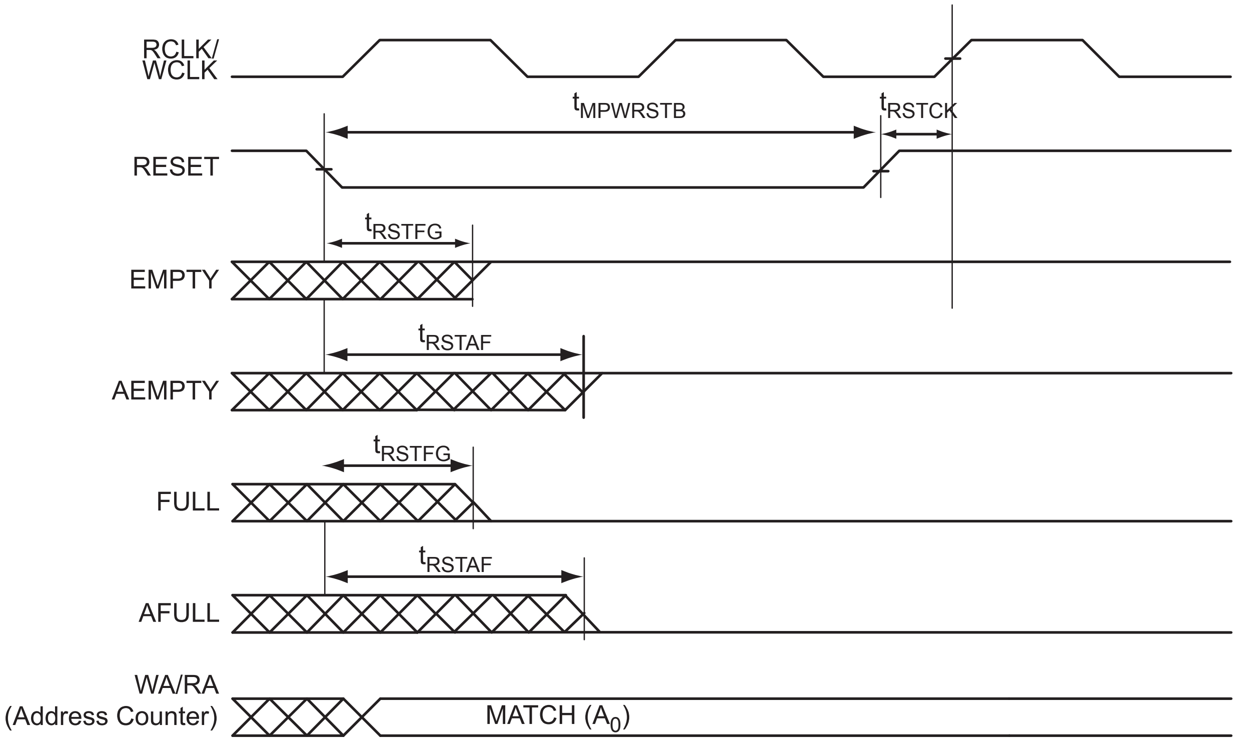

Figure 2-49 **• FIFO Reset**

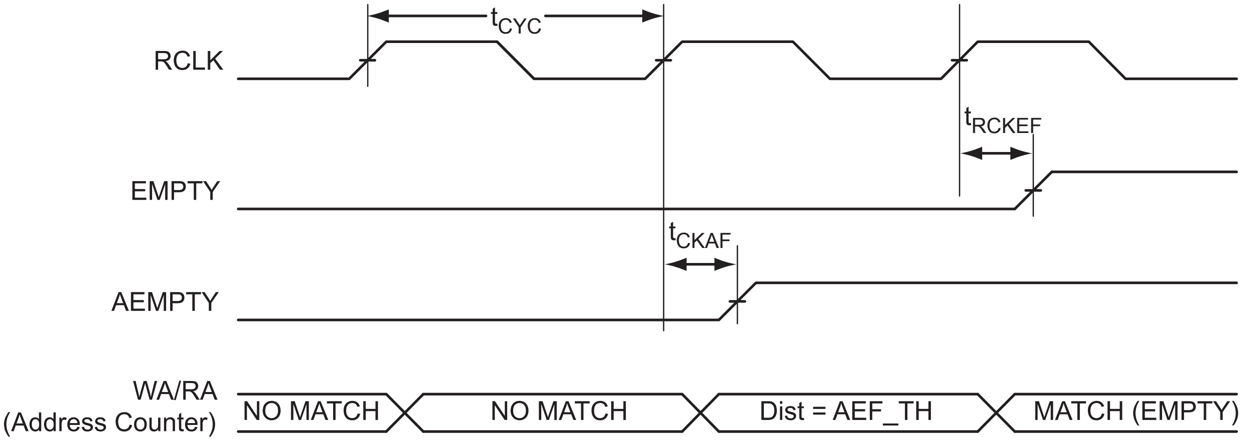

Figure 2-50 **• FIFO EMPTY Flag and AEMPTY Flag Assertion**

PQ208	
Pin Number	**A3PE1500 Function**
109	TRST
110	VJTAG
111	VMV3
112	GDA0/IO110NPB3V2
113	GDB0/IO109NPB3V2
114	GDA1/IO110PPB3V2
115	GDB1/IO109PPB3V2
116	GDC0/IO108NDB3V2
117	GDC1/IO108PDB3V2
118	IO105NDB3V2
119	IO105PDB3V2
120	IO101NDB3V1
121	IO101PDB3V1
122	GND
123	VCCIB3
124	GCC2/IO90PSB3V0
125	GCB2/IO89PSB3V0
126	NC
127	IO88NDB3V0
128	GCA2/IO88PDB3V0
129	GCA1/IO87PPB3V0
130	GND
131	VCCPLC
132	GCA0/IO87NPB3V0
133	VCOMPLC
134	GCB0/IO86NDB2V3
135	GCB1/IO86PDB2V3
136	GCC1/IO85PSB2V3
137	IO83NDB2V3
138	IO83PDB2V3
139	IO81PSB2V3
140	VCCIB2
141	GND
142	VCC
143	IO73NDB2V2
144	IO73PDB2V2
145	IO71NDB2V2
146	IO71PDB2V2
147	IO67NDB2V1
148	IO67PDB2V1
149	IO65NDB2V1
150	IO65PDB2V1
151	GBC2/IO60PSB2V0
152	GBA2/IO58PSB2V0
153	GBB2/IO59PSB2V0
154	VMV2
155	GNDQ
156	GND
157	VMV1
158	GNDQ
159	GBA1/IO57PDB1V3
160	GBA0/IO57NDB1V3
161	GBB1/IO56PDB1V3
162	GND
163	GBB0/IO56NDB1V3
164	GBC1/IO55PDB1V3
165	GBC0/IO55NDB1V3
166	IO51PDB1V2
167	IO51NDB1V2
168	IO47PDB1V1
169	IO47NDB1V1
170	VCCIB1
171	VCC
172	IO43PSB1V1
173	IO41PDB1V1
174	IO41NDB1V1
175	IO35PDB1V0
176	IO35NDB1V0
177	IO31PDB0V3
178	GND
179	IO31NDB0V3
180	IO29PDB0V3
181	IO29NDB0V3
182	IO27PDB0V3
183	IO27NDB0V3
184	IO23PDB0V2
185	IO23NDB0V2
186	VCCIB0
187	VCC
188	IO18PDB0V2
189	IO18NDB0V2
190	IO15PDB0V1
191	IO15NDB0V1
192	IO12PSB0V1
193	IO11PDB0V1
194	IO11NDB0V1
195	GND
196	IO08PDB0V1
197	IO08NDB0V1
198	IO05PDB0V0
199	IO05NDB0V0
200	VCCIB0
201	GAC1/IO02PDB0V0
202	GAC0/IO02NDB0V0
203	GAB1/IO01PDB0V0
204	GAB0/IO01NDB0V0
205	GAA1/IO00PDB0V0
206	GAA0/IO00NDB0V0
207	GNDQ
208	VMV0

PQ208	
Pin Number	A3PE3000 Function
118	IO134NDB3V2
119	IO134PDB3V2
120	IO132NDB3V2
121	IO132PDB3V2
122	GND
123	VCCIB3
124	GCC2/IO117PSB3V0
125	GCB2/IO116PSB3V0
126	NC
127	IO115NDB3V0
128	GCA2/IO115PDB3V0
129	GCA1/IO114PPB3V0
130	GND
131	VCCPLC
132	GCA0/IO114NPB3V0
133	VCOMPLC
134	GCB0/IO113NDB2V3
135	GCB1/IO113PDB2V3
136	GCC1/IO112PSB2V3
137	IO110NDB2V3
138	IO110PDB2V3
139	IO106PSB2V3
140	VCCIB2
141	GND
142	VCC
143	IO99NDB2V2
144	IO99PDB2V2
145	IO96NDB2V1
146	IO96PDB2V1
147	IO91NDB2V1
148	IO91PDB2V1
149	IO88NDB2V0
150	IO88PDB2V0
151	GBC2/IO84PSB2V0
152	GBA2/IO82PSB2V0
153	GBB2/IO83PSB2V0
154	VMV2
155	GNDQ
156	GND
157	VMV1
158	GNDQ
159	GBA1/IO81PDB1V4
160	GBA0/IO81NDB1V4
161	GBB1/IO80PDB1V4
162	GND
163	GBB0/IO80NDB1V4
164	GBC1/IO79PDB1V4
165	GBC0/IO79NDB1V4
166	IO74PDB1V4
167	IO74NDB1V4
168	IO70PDB1V3
169	IO70NDB1V3
170	VCCIB1
171	VCC
172	IO56PSB1V1
173	IO55PDB1V1
174	IO55NDB1V1
175	IO54PDB1V1
176	IO54NDB1V1
177	IO40PDB0V4
178	GND
179	IO40NDB0V4
180	IO37PDB0V4
181	IO37NDB0V4
182	IO35PDB0V4
183	IO35NDB0V4
184	IO32PDB0V3
185	IO32NDB0V3
186	VCCIB0
187	VCC
188	IO28PDB0V3
189	IO28NDB0V3
190	IO24PDB0V2
191	IO24NDB0V2
192	IO21PSB0V2
193	IO16PDB0V1
194	IO16NDB0V1
195	GND
196	IO11PDB0V1
197	IO11NDB0V1
198	IO08PDB0V0
199	IO08NDB0V0
200	VCCIB0
201	GAC1/IO02PDB0V0
202	GAC0/IO02NDB0V0
203	GAB1/IO01PDB0V0
204	GAB0/IO01NDB0V0
205	GAA1/IO00PDB0V0
206	GAA0/IO00NDB0V0
207	GNDQ
208	VMV0

FG324	
Pin Number	A3PE3000 FBGA
G1	GND
G2	IO287PDB7V1
G3	IO287NDB7V1
G4	IO283PPB7V1
G5	VCCIB7
G6	IO279PDB7V0
G7	IO291NPB7V2
G8	VCC
G9	IO26NDB0V3
G10	IO34NDB0V4
G11	VCC
G12	IO94NPB2V1
G13	IO98PDB2V2
G14	VCCIB2
G15	GCC0/IO112NPB2V3
G16	IO104PDB2V2
G17	IO104NDB2V2
G18	GND
H1	IO267PDB6V4
H2	VCCIB7
H3	IO283NPB7V1
H4	GFB1/IO274PPB7V0
H5	GND
H6	IO279NDB7V0
H7	VCC
H8	VCC
H9	GND
H10	GND
H11	VCC
H12	VCC
H13	IO98NDB2V2
H14	GND
H15	GCB1/IO113PDB2V3
H16	GCC1/IO112PPB2V3
H17	VCCIB2
H18	IO108PDB2V3

FG324	
Pin Number	A3PE3000 FBGA
J1	IO267NDB6V4
J2	GFA0/IO273NDB6V4
J3	VCOMPLF
J4	GFA2/IO272PDB6V4
J5	GFB0/IO274NPB7V0
J6	GFC0/IO275NDB7V0
J7	GFC1/IO275PDB7V0
J8	GND
J9	GND
J10	GND
J11	GND
J12	GCA2/IO115PDB3V0
J13	GCA1/IO114PDB3V0
J14	GCA0/IO114NDB3V0
J15	GCB0/IO113NDB2V3
J16	VCOMPLC
J17	IO120NPB3V0
J18	IO108NDB2V3
K1	IO263PDB6V3
K2	GFA1/IO273PDB6V4
K3	VCCPLF
K4	IO272NDB6V4
K5	GFC2/IO270PPB6V4
K6	GFB2/IO271PDB6V4
K7	IO271NDB6V4
K8	GND
K9	GND
K10	GND
K11	GND
K12	IO115NDB3V0
K13	GCB2/IO116PDB3V0
K14	IO116NDB3V0
K15	GCC2/IO117PDB3V0
K16	VCCPLC
K17	IO124NPB3V1
K18	IO120PPB3V0

FG324	
Pin Number	A3PE3000 FBGA
L1	IO263NDB6V3
L2	VCCIB6
L3	IO259PDB6V3
L4	IO259NDB6V3
L5	GND
L6	IO270NPB6V4
L7	VCC
L8	VCC
L9	GND
L10	GND
L11	VCC
L12	VCC
L13	IO132PDB3V2
L14	GND
L15	IO117NDB3V0
L16	IO128NPB3V1
L17	VCCIB3
L18	IO124PPB3V1
M1	GND
M2	IO255PDB6V2
M3	IO255NDB6V2
M4	IO251PPB6V2
M5	VCCIB6
M6	GEB0/IO235NDB6V0
M7	GEB1/IO235PDB6V0
M8	VCC
M9	IO192PPB4V4
M10	IO154NPB4V0
M11	VCC
M12	GDA0/IO153NPB3V4
M13	IO132NDB3V2
M14	VCCIB3
M15	IO134NDB3V2
M16	IO134PDB3V2
M17	IO128PPB3V1
M18	GND

FG484	
Pin Number	**A3PE1500 Function**
N17	IO91NPB3V0
N18	IO90NPB3V0
N19	IO91PPB3V0
N20	GNDQ
N21	IO93NDB3V0
N22	IO95PDB3V1
P1	NC
P2	IO183PDB6V2
P3	IO187NPB6V2
P4	IO184NPB6V2
P5	IO176PPB6V1
P6	IO182PDB6V1
P7	IO182NDB6V1
P8	VCCIB6
P9	GND
P10	VCC
P11	VCC
P12	VCC
P13	VCC
P14	GND
P15	VCCIB3
P16	GDB0/IO109NPB3V2
P17	IO97NDB3V1
P18	IO97PDB3V1
P19	IO99PDB3V1
P20	VMV3
P21	IO98PDB3V1
P22	IO95NDB3V1
R1	NC
R2	IO177PDB6V1
R3	VCC
R4	IO176NPB6V1
R5	IO174NDB6V0
R6	IO174PDB6V0
R7	GEC0/IO169NPB6V0
R8	VMV5
R9	VCCIB5
R10	VCCIB5
R11	IO135NDB5V0
R12	IO135PDB5V0
R13	VCCIB4
R14	VCCIB4
R15	VMV3
R16	VCCPLD
R17	GDB1/IO109PPB3V2
R18	GDC1/IO108PDB3V2
R19	IO99NDB3V1
R20	VCC
R21	IO98NDB3V1
R22	IO101PDB3V1
T1	NC
T2	IO177NDB6V1
T3	NC
T4	IO171PDB6V0
T5	IO171NDB6V0
T6	GEC1/IO169PPB6V0
T7	VCOMPLE
T8	GNDQ
T9	GEA2/IO166PPB5V3
T10	IO145NDB5V1
T11	IO141NDB5V0
T12	IO139NDB5V0
T13	IO119NDB4V1
T14	IO119PDB4V1
T15	GNDQ
T16	VCOMPLD
T17	VJTAG
T18	GDC0/IO108NDB3V2
T19	GDA1/IO110PDB3V2
T20	NC
T21	IO103PDB3V2
T22	IO101NDB3V1
U1	IO175PPB6V1
U2	IO173PDB6V0
U3	IO173NDB6V0
U4	GEB1/IO168PDB6V0
U5	GEB0/IO168NDB6V0
U6	VMV6
U7	VCCPLE
U8	IO166NPB5V3
U9	IO157PPB5V2
U10	IO145PDB5V1
U11	IO141PDB5V0
U12	IO139PDB5V0
U13	IO121NDB4V1
U14	IO121PDB4V1
U15	VMV4
U16	TCK
U17	VPUMP
U18	TRST
U19	GDA0/IO110NDB3V2
U20	NC
U21	IO103NDB3V2
U22	IO105PDB3V2
V1	NC
V2	IO175NPB6V1
V3	GND
V4	GEA1/IO167PDB6V0
V5	GEA0/IO167NDB6V0
V6	GNDQ
V7	GEC2/IO164PDB5V3
V8	IO157NPB5V2
V9	IO151NDB5V2
V10	IO151PDB5V2
V11	IO137NDB5V0
V12	IO137PDB5V0
V13	IO123NDB4V1
V14	IO123PDB4V1

FG676	
Pin Number	**A3PE1500 Function**
G13	IO21NDB0V2
G14	IO27PDB0V3
G15	IO35NDB1V0
G16	IO39PDB1V0
G17	IO51NDB1V2
G18	IO53NDB1V2
G19	VCCIB1
G20	GBA2/IO58PPB2V0
G21	GNDQ
G22	IO64NDB2V1
G23	IO64PDB2V1
G24	IO72PDB2V2
G25	IO72NDB2V2
G26	IO78PDB2V2
H1	IO208NDB7V2
H2	IO208PDB7V2
H3	IO209NDB7V2
H4	IO209PDB7V2
H5	IO219NDB7V3
H6	GAC2/IO219PDB7V3
H7	VCCIB7
H8	VCC
H9	VCCIB0
H10	VCCIB0
H11	VCCIB0
H12	VCCIB0
H13	VCCIB0
H14	VCCIB1
H15	VCCIB1
H16	VCCIB1
H17	VCCIB1
H18	VCCIB1
H19	VCC
H20	VCC
H21	IO58NPB2V0
H22	IO70PDB2V1

FG676	
Pin Number	**A3PE1500 Function**
H23	IO69PDB2V1
H24	IO76PDB2V2
H25	IO76NDB2V2
H26	IO78NDB2V2
J1	IO197NDB7V0
J2	IO197PDB7V0
J3	VMV7
J4	IO215NDB7V3
J5	IO215PDB7V3
J6	IO214PDB7V3
J7	IO214NDB7V3
J8	VCCIB7
J9	VCC
J10	VCC
J11	VCC
J12	VCC
J13	VCC
J14	VCC
J15	VCC
J16	VCC
J17	VCC
J18	VCC
J19	VCCIB2
J20	IO62PDB2V0
J21	IO62NDB2V0
J22	IO70NDB2V1
J23	IO69NDB2V1
J24	VMV2
J25	IO80PDB2V3
J26	IO80NDB2V3
K1	IO195PDB7V0
K2	IO199NDB7V1
K3	IO199PDB7V1
K4	IO205NDB7V1
K5	IO205PDB7V1
K6	IO217PDB7V3

FG676	
Pin Number	**A3PE1500 Function**
K7	IO217NDB7V3
K8	VCCIB7
K9	VCC
K10	GND
K11	GND
K12	GND
K13	GND
K14	GND
K15	GND
K16	GND
K17	GND
K18	VCC
K19	VCCIB2
K20	IO65PDB2V1
K21	IO65NDB2V1
K22	IO74PDB2V2
K23	IO74NDB2V2
K24	IO75PDB2V2
K25	IO75NDB2V2
K26	IO84PDB2V3
L1	IO195NDB7V0
L2	IO198PPB7V0
L3	GNDQ
L4	IO201PDB7V1
L5	IO201NDB7V1
L6	IO210NDB7V2
L7	IO210PDB7V2
L8	VCCIB7
L9	VCC
L10	GND
L11	GND
L12	GND
L13	GND
L14	GND
L15	GND
L16	GND

FG896	
Pin Number	**A3PE3000 Function**
J5	IO295NDB7V2
J6	IO299NDB7V3
J7	VCCIB7
J8	VCCPLA
J9	VCC
J10	IO04NPB0V0
J11	IO18NDB0V2
J12	IO20NDB0V2
J13	IO20PDB0V2
J14	IO32NDB0V3
J15	IO32PDB0V3
J16	IO42PDB1V0
J17	IO44NDB1V0
J18	IO44PDB1V0
J19	IO54NDB1V1
J20	IO54PDB1V1
J21	IO76NPB1V4
J22	VCC
J23	VCCPLB
J24	VCCIB2
J25	IO90PDB2V1
J26	IO90NDB2V1
J27	GBB2/IO83PDB2V0
J28	IO83NDB2V0
J29	IO91PDB2V1
J30	IO91NDB2V1
K1	IO288NDB7V1
K2	IO288PDB7V1
K3	IO304NDB7V3
K4	IO304PDB7V3
K5	GAB2/IO308PDB7V4
K6	IO308NDB7V4
K7	IO301PDB7V3
K8	IO301NDB7V3
K9	GAC2/IO307PPB7V4
K10	VCC

FG896	
Pin Number	**A3PE3000 Function**
K11	IO04PPB0V0
K12	VCCIB0
K13	VCCIB0
K14	VCCIB0
K15	VCCIB0
K16	VCCIB1
K17	VCCIB1
K18	VCCIB1
K19	VCCIB1
K20	IO76PPB1V4
K21	VCC
K22	IO78PPB1V4
K23	IO88NDB2V0
K24	IO88PDB2V0
K25	IO94PDB2V1
K26	IO94NDB2V1
K27	IO85PDB2V0
K28	IO85NDB2V0
K29	IO93PDB2V1
K30	IO93NDB2V1
L1	IO286NDB7V1
L2	IO286PDB7V1
L3	IO298NDB7V3
L4	IO298PDB7V3
L5	IO283PDB7V1
L6	IO291NDB7V2
L7	IO291PDB7V2
L8	IO293PDB7V2
L9	IO293NDB7V2
L10	IO307NPB7V4
L11	VCC
L12	VCC
L13	VCC
L14	VCC
L15	VCC
L16	VCC

FG896	
Pin Number	**A3PE3000 Function**
L17	VCC
L18	VCC
L19	VCC
L20	VCC
L21	IO78NPB1V4
L22	IO104NPB2V2
L23	IO98NDB2V2
L24	IO98PDB2V2
L25	IO87PDB2V0
L26	IO87NDB2V0
L27	IO97PDB2V1
L28	IO101PDB2V2
L29	IO103PDB2V2
L30	IO119NDB3V0
M1	IO282NDB7V1
M2	IO282PDB7V1
M3	IO292NDB7V2
M4	IO292PDB7V2
M5	IO283NDB7V1
M6	IO285PDB7V1
M7	IO287PDB7V1
M8	IO289PDB7V1
M9	IO289NDB7V1
M10	VCCIB7
M11	VCC
M12	GND
M13	GND
M14	GND
M15	GND
M16	GND
M17	GND
M18	GND
M19	GND
M20	VCC
M21	VCCIB2
M22	NC

Revision	Changes	Page
Revision 10 (March 2012)	The "In-System Programming (ISP) and Security" section and "Security" section were revised to clarify that although no existing security measures can give an absolute guarantee, Microsemi FPGAs implement the best security available in the industry (SAR 34669).	I, 1-1
	The Y security option and Licensed DPA Logo were added to the "ProASIC3E Ordering Information" section. The trademarked Licensed DPA Logo identifies that a product is covered by a DPA counter-measures license from Cryptography Research (SAR 34727).	III
	The following sentence was removed from the "Advanced Architecture" section: "In addition, extensive on-chip programming circuitry allows for rapid, single-voltage (3.3 V) programming of IGLOOe devices via an IEEE 1532 JTAG interface" (SAR 34689).	1-3
	The "Specifying I/O States During Programming" section is new (SAR 34699).	1-6
	VCCPLL in Table 2-2 • Recommended Operating Conditions [1] was corrected from "1.4 to 1.6 V" to "1.425 to 1.575 V" (SAR 33851). The T_J symbol was added to the table and notes regarding T_A and T_J were removed. The second of two parameters in the VCCI and VMV row, called "3.3 V DC supply voltage," was corrected to "3.0 V DC supply voltage" (SAR 37227).	2-2
	The reference to guidelines for global spines and VersaTile rows, given in the "Global Clock Contribution—P_{CLOCK}" section, was corrected to the "Spine Architecture" section of the Global Resources chapter in the *ProASIC3E FPGA Fabric User's Guide* (SAR 34735).	2-9
	t_{DOUT} was corrected to t_{DIN} in Figure 2-3 • Input Buffer Timing Model and Delays (example) (SAR 37109).	2-13
	The typo related to the values for 3.3 V LVCMOS Wide Range in Table 2-17 • Summary of I/O Timing Characteristics—Software Default Settings was corrected (SAR 37227).	2-19
	The notes regarding drive strength in the "Summary of I/O Timing Characteristics – Default I/O Software Settings" section and "3.3 V LVCMOS Wide Range" section and tables were revised for clarification. They now state that the minimum drive strength for the default software configuration when run in wide range is ±100 µA. The drive strength displayed in software is supported in normal range only. For a detailed I/V curve, refer to the IBIS models (SAR 34763).	2-18, 2-27

Datasheet Categories

Categories

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "ProASIC3E Device Status" table on page II, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

Product Brief

The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

Advance

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

Preliminary

The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

Production

This version contains information that is considered to be final.

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